EMH6 / UMH6N / IMH6A

Transistors

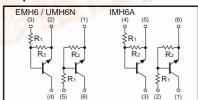
General purpose (dual digital transistors)

EMH6 / UMH6N / IMH6A

Features

 Two DTC144E chips in a EMT or UMT or SMT package.

Equivalent circuit



Package, marking, and packaging specifications

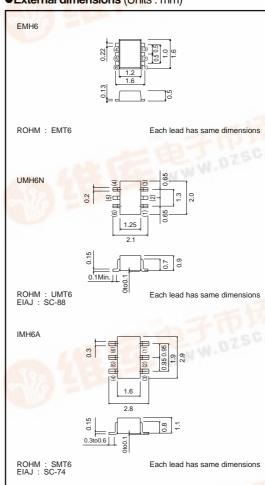
Туре	EMH6	UMH6N	IMH6A
Package	EMT6	UMT6	SMT6
Marking	H6	H6	H6
Code	T2R	TR	T108
Basic ordering unit (pieces)	8000	3000	3000

● Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Limits	Unit	
Supply voltage		Vcc	50	V	
Input voltage		Vin	40	V	
		VIN	-10		
Output current		lo	30	mA	
Power dissipation	EMH6 / UMH6N	Pd	150(TOTAL)	mW *1 *2	
	IMH6A		300(TOTAL)		
Junction temperature		Tj	150	°C	
Storage temperature		Tstg	-55~+150	°C	

^{1 120}mW per element must not be exceeded

●External dimensions (Units : mm)



● Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions		
Input voltage	VI (off)	_	-	0.5	V	Vcc=5V, Io=100μA		
	VI (on)	3	-	101-11		Vo=0.3V, Io=2mA		
Output voltage	Vo (on)	1	0.1	0.3	V	Io/I=10mA/0.5mA		
Input current		C (- III	-	0.18	mA	VI=5V		
Output current	IO (off)	-	_	0.5	μΑ	Vcc=50V, Vi=0V		
DC current gain	Gı	68	-	-	-	Io/Vo=5mA/5V		
Input resistance	R ₁	32.9	47	61.1	kΩ	_		
Resistance ratio	R2/R1	0.8	1	1.2	-	_		
Transition frequency	f⊤	_	250	_	MHz	Vce=10V, Ie=-5mA, f=100MHz *		

*Transition frequency of the device

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